## NSN 5961-01-339-3273

**Fiig:** A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-339-3273 **Inclosure Material:** Metal and plastic **Overall Length:** 15.8 millimeters **Terminal Length:** 13.5 millimeters **Overall Height:** 4.5 millimeters **Overall Width:** 10.3 millimeters **End Application:** Tactical air operations central an/tyq-2 (v) 1 **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method:** Terminal and unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 repetitive peak reverse voltage and 500.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 100.00 amperes peak forward surge current absolute and 7.50 amperes forward current, total rms universal and 12.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No